Highly tunable second-harmonic generation in all-optically poled silicon nitride waveguides

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Received 23 January 2020; revised 28 February 2020; accepted 28 February 2020; posted 2 March 2020 (Doc. ID 387603); published 24 March 2020

The availability of nonlinear parametric processes, such as frequency conversion in photonics integrated circuits is essential. In this contribution, we demonstrate a highly tunable second-harmonic generation in a fully complementary metal–oxide–semiconductor (CMOS)-fabrication-compatible silicon nitride integrated photonic platform. We induce the second-order nonlinearity using an all-optical poling technique with the second-harmonic light generated in the fundamental mode, and a narrow quasi-phase-matching (QPM) spectrum by avoiding higher-order mode mixing. We are then able to broadly tune the phase-matched pump wavelength over the entire C-band (1540 nm to 1560 nm) by varying the poling conditions. Fine-tuning of QPM is enabled by thermo-optic effect with the tuning slope $\Delta \lambda / \Delta T$ in our device being 113.8 pm°C. In addition, we exploit the measurable variation of the 3 dB QPM bandwidth to confirm how the length of the all-optically inscribed grating varies with exposure time. © 2020 Optical Society of America

https://doi.org/10.1364/OL.387603

Reaching efficient wavelength conversion on an integrated photonics platform is currently an actively pursued goal in photonics. Wavelength conversion could be used in a wide variety of applications, such as frequency comb generation [1,2], up-conversion detection [3], and quantum communications [4,5] to name a few. The generation of new optical frequencies comes from the nonlinear optical properties of the employed material. The most frequent approach in integrated photonics for the mentioned purpose is to leverage the third-order ($\chi^{(3)}$) nonlinearity, which where new optical carriers are generated through four-wave-mixing (FWM) [6]. However, for efficient conversion through FWM high optical powers and strong confinement are necessary. Therefore, a great deal of effort is put into utilizing second-order ($\chi^{(2)}$) nonlinearity, which is several orders of magnitude more efficient than $\chi^{(3)}$ at the same levels of optical power. $\chi^{(2)}$ also gives access to many important effects in optics, including second harmonic (SH) generation. Unfortunately, most of the complementary metal–oxide–semiconductor (CMOS)-fabrication-compatible platforms for photonic integrated circuit development use materials that are either amorphous or centrosymmetric thus lacking second-order nonlinearity. To enable $\chi^{(2)}$ functionality in integrated photonics several approaches have been suggested and demonstrated. One approach involves using materials that belong to the non-centrosymmetric class. Here the highest efficiency has been reached by using III-V materials such as GaAs of AlGaAs [7–9]. Unfortunately, there still is a great trade-off between high efficiency and loss in such III-V waveguides. Lithium niobate is also emerging rapidly as a material for building nonlinear integrated circuits. It has a broad transmission range and a high nonlinear coefficient [10], moreover, less than 0.2 dB/cm loss has been demonstrated on a lithium niobate-on-insulator platform [11]. The greatest issue when using either III-V, lithium niobate, or other non-centrosymmetric material is that intermodal phase-matching has to be implemented, which for the case of SH generation means that the SH is generated in a higher-order mode while the pump is in the fundamental one [12]. This limits the conversion efficiency (CE) due to a reduced overlap integral and high loss of higher-order SH modes. Moreover, such an approach requires dispersion engineering in order to match the optical phases of pump and SH at particular wavelengths. The latter issue can be overcome by quasi-phase-matching (QPM), which is a technique for compensating the phase mismatch of pump and SH through creating a periodic structure in a nonlinear medium. QPM has been applied widely in waveguides possessing either $\chi^{(2)}$ or $\chi^{(3)}$ nonlinearity [9,10,13,14]. All aforementioned show potential for reaching high efficiencies, yet suffer from lack of flexibility and typically require complex fabrication steps involving high resolution lithography.

Considerable attention has been devoted to silicon nitride ($\text{Si}_3\text{N}_4$) which is currently one of the most mature CMOS-compatible platforms for integrated photonics. $\text{Si}_3\text{N}_4$ waveguides have been widely used for $\chi^{(3)}$ nonlinearity with the demonstration of optical frequency comb generation [1,2,15], ultra-low loss resonators [16–18], entangled photon-pair generation [19], as well as low pulse energy supercontinuum generation in the near [20] and mid-infrared [21]. Recently we showed that efficient QPM and SH generation can be achieved in $\text{Si}_3\text{N}_4$ waveguides by using all-optical poling [22]. During all-optical poling an effective $\chi^{(2)}$ builds up spontaneously in the presence of a high intensity coherent pump and weak SH
due to the coherent photogalvanic effect [23,24]. Additional recent studies of all-optical poling of Si$_3$N$_4$ waveguides have confirmed the presence of an effective $\chi^{(2)}$ grating and given insight into its formation process [25–28]. The key strength of the used approach is that it allows automatic QPM of fundamental modes at pump and SH without the need to engineer the dispersion of the waveguide. Despite the latter, the parameters of the employed waveguide can have significant influence on QPM properties. We have reported indications of energy transfer to SH modes other than the fundamental one. This is suggested to be a result of mode distortions or mode mixing experienced in the waveguide’s bends leading to a broadening of the expected QPM spectral response. Mode mixing can be avoided by reducing the mode overlap between the fundamental mode of the FH with higher-order modes at SH in the waveguide bends [27]. Importantly, the all-optical poling introduces second-order nonlinearity in the waveguide without any obvious change of other properties such as propagation loss. In this contribution we demonstrate the flexible broadband spectral tuning capabilities of QPM in all-optically poled Si$_3$N$_4$ waveguides as well as highlight the importance of thermal stability of the chip during the all-optical poling process.

The Si$_3$N$_4$ waveguide used in this study has dimensions of 0.57 $\mu$m $\times$ 0.81 $\mu$m and was fabricated by LIGENTEC using its AN800 technology platform [29]. The 81 $\mu$m long waveguide is folded in nine meanders on a 10 mm chip by using curved sections with a radius of 75 $\mu$m. The waveguide dimensions were chosen such that SH is generated in the fundamental mode, and QPM broadening due to mode mixing would not be present [27]. The waveguide was poled using an optical setup described in Ref. [22]. Here the continuous wave (CW) light from a coherent tunable light source in the C-band is shaped by a Mach–Zehnder modulator into a 1-ns 5-MHz pulse train and then amplified in two consecutive stages. This pulsed pump is then coupled into the waveguide using a lensed fiber. The output light of the chip is collected using a 20× microscope objective and delivered to pump and SH photodetectors using dichroic mirrors. The light propagation loss is measured to be 0.33 dB/cm at 1550 nm and 0.73 dB/cm at 775 nm. During the all-optical poling procedure, the temperature of the chip is kept constant at $T_F = 30^\circ$C using a PID controller and a Peltier module. In Fig. 1(a) the growth of type-0 SH CE versus time is shown when a high intensity TE polarized coherent pump at 1550 nm with maximum peak-power of 29.4 W is coupled into the waveguide. As evident, the SH intensity grows and saturates at 0.5%/W in less than 10 min. The efficiency could be further increased by raising the coupled pump power during poling [27]. We interrupt the all-optical poling process at times indicated by red circles in Fig. 1(a) to study the properties of the QPM. At each interruption instant, the SH spectral response induced by the low CW probe was recorded around the pump wavelength. The CE is fit with a sinc-squared function as shown by the lines in Figs. 1(b)–1(e) according to the following equation:

$$\text{CE} = \frac{\left(\frac{\omega L_g \chi_{eff}^{(2)}}{2e_\omega \epsilon_0 n_{\omega}^2 n_{2\omega}^2 S} \left(\frac{\sin \left(\Delta \beta L_g/2\right)}{\Delta \beta L_g/2}\right)^2 \right)^2}{10^{-6}}.$$  

where $\omega$ is the pump frequency, $L_g$ is the grating length, $\chi_{eff}^{(2)}$ is the effective nonlinearity, $n_{\omega}$ and $n_{2\omega}$ are the refractive indexes at pump and SH wavelengths, respectively. $S$ is the effective area, and $\Delta \beta$ is the propagation constant mismatch [30]. The $\Delta \beta$ after all-optical poling of the waveguide can be written as

$$\Delta \beta = \beta_{2\omega} - 2\beta_{\omega} - \frac{2\pi}{\Lambda},$$  

where $\Lambda$ is the grating period, and $\beta_{2\omega}$ and $\beta_{\omega}$ are the propagation constants at the SH and fundamental harmonic, respectively [31]. The fits of CE spectral responses allow for the extraction of $\Lambda$, $L_g$, as well as $\chi_{eff}^{(2)}$. The obtained data is summarized in Table 1.

![Diagram](image.png)

**Fig. 1.** (a) Growth of CE during all-optical poling as a function of time. The red marks indicate instants ($t_1$, $t_2$, $t_3$, and $t_4$) at which the poling is interrupted for CE spectra measurements. Inset: TPM image of the grating at time $t_1$. (b)–(e) Measured and fitted CE spectra (dors) at interrupt instants $t_1$, $t_2$, $t_3$, and $t_4$, respectively.

<table>
<thead>
<tr>
<th>CE (%)/W</th>
<th>$t_1$</th>
<th>$t_2$</th>
<th>$t_3$</th>
<th>$t_4$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$10^{-6}$</td>
<td>20.3</td>
<td>21.8</td>
<td>34.8</td>
<td>40.8</td>
</tr>
<tr>
<td>$B W_{\text{eff}}$ (nm)</td>
<td>0.38</td>
<td>0.35</td>
<td>0.22</td>
<td>0.17</td>
</tr>
<tr>
<td>$\Lambda$ (\mu m)</td>
<td>3.24</td>
<td>3.24</td>
<td>3.24</td>
<td>3.24</td>
</tr>
<tr>
<td>Max CE (%)/W</td>
<td>0.005</td>
<td>0.01</td>
<td>0.08</td>
<td>0.49</td>
</tr>
<tr>
<td>$\chi_{eff}^{(2)}$ (pm/V)</td>
<td>0.011</td>
<td>0.015</td>
<td>0.024</td>
<td>0.058</td>
</tr>
</tbody>
</table>

At each interruption instant, the SH spectral response induced by the low CW probe was recorded around the pump wavelength. The CE is fit with a sinc-squared function as shown by the lines in Figs. 1(b)–1(e) according to the following equation:

$$\text{CE} = \frac{\left(\frac{\omega L_g \chi_{eff}^{(2)}}{2e_\omega \epsilon_0 n_{\omega}^2 n_{2\omega}^2 S} \left(\frac{\sin \left(\Delta \beta L_g/2\right)}{\Delta \beta L_g/2}\right)^2 \right)^2}{10^{-6}}.$$  

where $\omega$ is the pump frequency, $L_g$ is the grating length, $\chi_{eff}^{(2)}$ is the effective nonlinearity, $n_{\omega}$ and $n_{2\omega}$ are the refractive indexes at pump and SH wavelengths, respectively. $S$ is the effective area, and $\Delta \beta$ is the propagation constant mismatch [30]. The $\Delta \beta$ after all-optical poling of the waveguide can be written as

$$\Delta \beta = \beta_{2\omega} - 2\beta_{\omega} - \frac{2\pi}{\Lambda},$$  

where $\Lambda$ is the grating period, and $\beta_{2\omega}$ and $\beta_{\omega}$ are the propagation constants at the SH and fundamental harmonic, respectively [31]. The fits of CE spectral responses allow for the extraction of $\Lambda$, $L_g$, as well as $\chi_{eff}^{(2)}$. The obtained data is summarized in Table 1.

As evident from Figs. 1(b)–1(e), the bandwidth of the SH spectrum ($B W_{\text{eff}}$) becomes narrower with poling time. This narrowing of the bandwidth is due to an increase of the grating length as the waveguide poling efficiency increases [27]. At time $t_4$ we performed two-photon microscopy (TPM) imaging of the $\chi^{(2)}$ grating [see inset Fig. 1(a)]. The retrieved $\chi^{(2)}$ grating period from TPM measurements is estimated to
be 3.34 ± 0.10 µm, in very good agreement with the values obtained from the fitting of the CE spectra (see Table 1).

The broadband tuning of QPM is enabled by poling the waveguide at different wavelengths, as the A will automatically adjust due to the change in propagation constants. After poling the waveguide using a 1550 nm pump and measuring the CE spectrum, we repeat the all-optical poling process in the same waveguide using a 1540 nm and a 1560 nm pump with peak powers of 26.2 W and 28.1 W, respectively. The recorded CE in %/W at each poling wavelength is plotted in Fig. 2(a). As evident, SH saturation in each case is reached in a time span of less than 10 min. During each consecutive all-optical poling at new wavelength the previously inscribed grating is erased, and no response at the previous poling wavelength is measurable.

From Figs. 2(a)–2(c), it is evident that even small differences in used poling pump power has significant influence on the saturation CE. It is once again confirmed that the maximal reachable efficiency grows exponentially with the increase in used pump peak power [27]. The maximum CE is therefore lowest (0.0023%/W) for a 1540 nm poling. We also obtain 0.16%/W at 1560 nm and 0.49%/W at 1550 nm. In Fig. 2(d) we plot the SH spectral responses after each poling step. Clearly, QPM inside the waveguide adjusts to match to the pump used during poling, and we did not measure any signature of the previously inscribed grating. In addition to the variation in maximum CE, we can also measure a change in the 3 dB bandwidth which follows the same principle observed in Fig. 1.

Broad tuning of the QPM conditions can therefore be obtained by re-poling of the waveguide. We show here coverage of the entire C-band, limited only by the bandwidth of the amplifier. We expect that a much broader tuning range can be reached. For example, successful poling of SiN waveguides has also been demonstrated using 1064 nm light source [25]. In addition, as a demonstration, we first poled the waveguide at 30°C using a 1560 nm pump wavelength. We then perform probing of the QPM spectrum with a CW wave for different temperature settings. In Fig. 3(a), the normalized SH spectra for five temperatures, from 25°C to 45°C, are plotted. Note that we performed the five measurements in random order. Also, while the normalized spectra are shown here, we did not measure any significant variations in the actual maximum CE value. From sinc-squared fits of the experimental data, we extract the wavelength at which the maximal CE takes place.

The measured phase-matched pump wavelength as a function of temperature is plotted in Fig. 3(b). The tuning slope Δλ/ΔT from the linear fit is calculated to be 113.8 pm/°C.

The thermal tuning is enabled by the thermo-optic effect in the waveguide’s cladding and core. Given the phase matching condition in Eq. (2), and assuming small variations in the refractive index difference as the temperature is changed by ΔT, the change in maximal CE wavelength Δλ is with respect to the initial pump wavelength λ_p can be calculated using the following equation:

$$\Delta \lambda = \frac{\lambda_p}{\Delta n_{eff}} \frac{\partial \Delta n_{eff}}{\partial T} \Delta T,$$

where Δn_{eff} is the absolute difference between the effective refractive indexes at FH and SH wavelengths. In a waveguide with cross-section 0.57 µm x 0.81 µm initially poled using a pump wavelength of 1560 nm, the Δn_{eff} is calculated to be 0.2594. Based on Eq. (3) and the experimentally measured slope, the $\partial \Delta n_{eff}/\partial T$ is estimated at 1.89 · 10⁻⁵ K⁻¹. The thermal tuning slope will vary with the dimensions of the all-optically poled waveguide. The size of the waveguide determines the $\partial \Delta n_{eff}/\partial T$ as well as Δn_{eff}. For waveguides with a larger cross-section, the Δn_{eff} will be smaller, while the $\partial \Delta n_{eff}/\partial T$ will become increasingly determined by the thermo-optic properties of the core. It is also important to note that increasing the operating temperature of the waveguide will reduce the lifetime of the inscribed grating [27]. In addition, we observed that a change in coupling conditions of 1 dB (due to in-coupling...
fluctuations) can significantly influence the measured CE as well as the poling curve. We believe this is due to temperature variations despite having temperature stabilization. Indeed for these measurements, and given the ~0.3 nm bandwidth of the QPM spectrum, only 1 deg C variation in temperature causes a 3 dB reduction in the SH response. The thermal stabilization of the sample holder might be too slow under such small temperature changes, which can explain oscillations in CE sometimes observed during poling [see Fig. 3(a)]. Thermal stability of the chip during the all-optical poling process is therefore of critical importance to avoid drifts and overall decrease in efficiency.

To conclude, we show a nanophotonic all-optically poled Si$_3$N$_4$ waveguide with induced second-order nonlinearity for tunable and efficient SH generation. We measured a CE of 0.49%/W in a waveguide allowing for narrow sinc-shaped pulse generation, which narrows and increases in efficiency, a clear confirmation that the grating grows in length and strength during the poling process. Broadband tuning of QPM is enabled by changing the pump wavelength used during poling, owing to the highly flexible and reconfigurable nature of waveguides for obtaining QPM at the necessary wavelength. Owing to the high quality of QPM, we observed the evolution of the CE spectrum during poling, which narrows and increases in efficiency, a clear confirmation that the grating grows in length and strength during the poling process. Broadband tuning of QPM after poling is enabled by thermo-optic effects. The tuning slope $\Delta \lambda / \Delta T$ in our device is measured to be 113.8 pm/°C which is of the same order of magnitude as achieved in lithium niobate [12,31].

Funding. European Research Council (PISSARRO ERC-2017-CoG771647).

Disclosures. The authors declare no conflicts of interest.

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